

KoHS

# Dual Output Fixed Output LDO Regulators

## BA3258HFP BA33Dxx series

#### General Description

The BA3258HFP, BA33D15HFP, BA33D18HFP are fixed 2-output low-saturation regulators with a voltage accuracy at both outputs of  $\pm 2\%$ . These series incorporate both overcurrent protection and thermal shutdown (TSD) circuits in order to prevent damage due to output short-circuiting and overloading, respectively.

#### Features

- Output voltage accuracy: ±2%.
- A ceramic capacitor can be used to prevent output oscillation (BA3258HFP).
- High Ripple Rejection (BA33Dxx Series)
- Built-in thermal shutdown circuit
- Built-in overcurrent protection circuit

## •Key Specifications

,			
	Input Power Sup	ply Voltage:	
		BA3258HFP	14.0V(Max.)
		BA33Dxx Series	16.0V(Max.)
	Output voltage ra	ange:	Fixed
	Output current:	BA3258HFP	1A (Max.)
		BA33Dxx Series	0.5A(Max.)
	Operating tempe	erature range:	
		BA3258HFP	-30°C to 85°C
		BA33Dxx Series	-25°C to 105°C

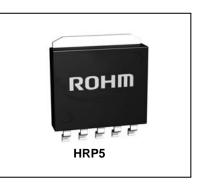
## Applications

FPDs, TVs, PCs, DSPs in DVDs and CDs



W (Typ.) x D (Typ.) x H (Max.) 9.395mm x 10.54 mm x 2.005mm

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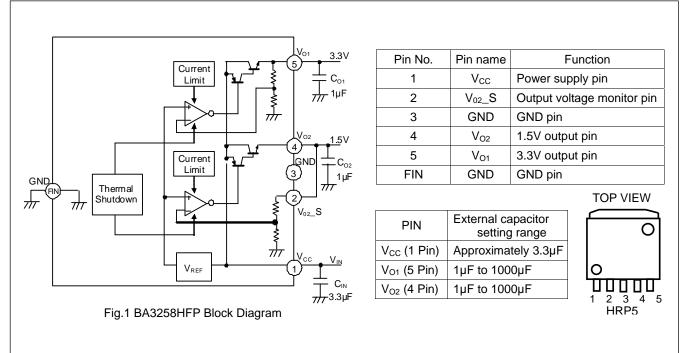
•	Orderi	ng Info	rmatio	n								
	В	А	3	х	х	х	Н	F	Ρ	-	TR	
	Part Numb	ber					Packa HFP:F	0				nd forming specification ed tape and reel

## ●Lineup

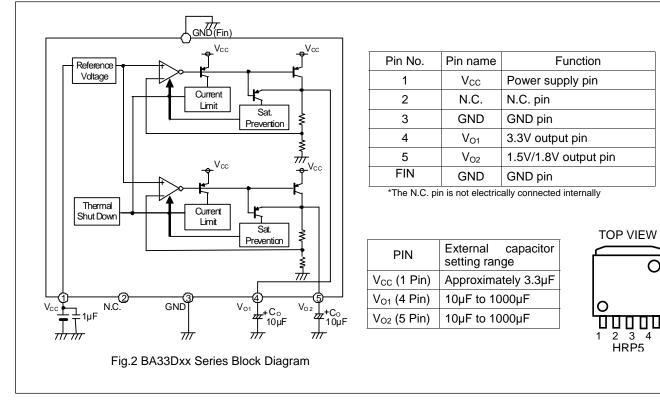
Maximum output current (Max.)	Output Voltage 1 (Typ.)	Output Voltage 2 (Typ.)	Package		Orderable Part Number
1A	3.3V	1.5V			BA3258HFP-TR
0.5A	3.3V	1.5V	HRP5	Reel of 2000	BA33D15HFP-TR
0.5A	3.3V	1.8V			BA33D18HFP-TR

OProduct structure : Silicon monolithic integrated circuit OThis product is not designed protection against radioactive rays.

## Block Diagrams / Standard Example Application Circuits / Pin Configurations / Pin Descriptions BA3258HFP



BA33DxxSeries



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## •Absolute Maximum Ratings

BA3258HFP			
Parameter	Symbol	Ratings	Unit
Applied voltage	V <sub>CC</sub>	15 <sup>*1</sup>	V
Power dissipation	Pd <sup>*2</sup>	2300 <sup>*2</sup>	mW
Operating temperature range	Topr	−30 to 85	°C
Ambient storage temperature	Tstg	−55 to 150	°C
Maximum junction temperature	Tjmax	150	°C

#### BA33Dxx Series

DAGGDAX Genes							
Parameter	Symbol	Ratings	Unit				
Applied voltage	V <sub>CC</sub>	18 <sup>*1</sup>	V				
Power dissipation	Pd <sup>*2</sup>	2300 <sup>*2</sup>	mW				
Operating temperature range	Topr	-25 to 105	°C				
Ambient storage temperature	Tstg	−55 to 150	°C				
Maximum junction temperature	Tjmax	150	°C				

\*1 Must not exceed Pd

\*2. Derated at 18.4 mW/°C at Ta>25°C when mounted on a glass epoxy board (70 mm  $\times$  70 mm  $\times$  1.6 mm)

## Recommended Operating Ratings

BA3258HFP

Parameter	Symbol		Unit		
Falametei	Symbol	Min.	Тур.	Max.	Unit
Input power supply voltage	V <sub>CC</sub>	4.75	-	- 14.0	
3.3 V output current	I <sub>O1</sub>	-	-	1	А
1.5 V output current	I <sub>O2</sub>	-	-	1	А

## BA33DxxSeries

Parameter	Symbol		6	Unit	
Falametei	Symbol	Min.	Тур.	Max.	Unit
Input power supply voltage	V <sub>CC</sub>	4.1	-	16.0	V
3.3 V output current	I <sub>O1</sub>	-	-	0.5	А
1.5V output current	I <sub>O2</sub>	-	-	0.5	А
1.8 V output current	I <sub>O2</sub>	-	-	0.5	А

## •Electrical Characteristics

BA3258HFP (Unless otherwise specified, Ta =  $25^{\circ}$ C, V<sub>CC</sub> = 5 V)

Deremeter	Symbol		Limits		l locit	Conditions
Parameter	Symbol	Min.	Тур.	Max.	Unit	
Bias current	IB	-	3	5	mA	I <sub>O1</sub> =0mA,I <sub>O2</sub> =0mA
[3.3 V Output Block]						
Output voltage1	V <sub>O1</sub>	3.234	3.300	3.366	V	I <sub>01</sub> =50mA
Minimum output voltage difference 1	$\Delta V_{D1}$	-	1.1	1.3	V	I <sub>01</sub> =1A,V <sub>CC</sub> =3.8V
Output current capacity 1	I <sub>O1</sub>	1.0	-	-	Α	
Ripple rejection 1	R.R.1	46	52	-	dB	f=120Hz,ein=0.5Vp-p,I <sub>01</sub> =5mA
Input stability 1	Reg.I1	-	5	15	mV	V <sub>CC</sub> =4.75→14V,I <sub>O1</sub> =5mA
Load stability 1	Reg.L1	-	5	20	mV	I <sub>O1</sub> =5mA→1A
Temperature coefficient of output voltage 1 <sup>*3</sup>	T <sub>CVO1</sub>	-	±0.01	-	%/°C	I <sub>01</sub> =5mA,Tj=0°C to 85°C
[1.5 V Output Block]						
Output voltage 2	V <sub>O2</sub>	1.470	1.500	1.530	V	I <sub>02</sub> =50mA
Output current capacity 2	I <sub>O2</sub>	1.0	-	-	Α	
Ripple rejection 2	R.R.2	46	52	-	dB	f=120Hz,ein=0.5Vp-p,I <sub>02</sub> =5mA
Input stability 2	Reg.l2	-	5	15	mV	V <sub>CC</sub> =4.1→14V,I <sub>O2</sub> =5mA
Load stability 2	Reg.L2	-	5	20	mV	I <sub>O2</sub> =5mA→1A
Temperature coefficient of output voltage 2 <sup>*3</sup>	T <sub>CVO2</sub>	-	±0.01	-	%/°C	I <sub>02</sub> =5mA,Tj=0°C to 125°C

\*3: Not 100% tested.

## Electrical Characteristics - continued

BA33Dxx Series (Unless otherwise specified, Ta =  $25^{\circ}$ C, V<sub>CC</sub> = 5 V)

			Limits					
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions		
Bias current	Ι <sub>Β</sub>	-	0.7	1.6	mA	I <sub>01</sub> =0mA,I <sub>02</sub> =0mA		
[3.3V Output Block]								
Output voltage 1	V <sub>01</sub>	3.234	3.300	3.366	V	I <sub>01</sub> =250mA		
Minimum output voltage difference 1	$\Delta V_{\text{D1}}$	Ι	0.25	0.50	V	I <sub>01</sub> =250mA,V <sub>CC</sub> =3.135V		
Output current capacity 1	I <sub>O1</sub>	0.5	-	-	А			
Ripple rejection 1	R.R.1	50	58	-	dB	f=120Hz,ein=1Vp-p,I <sub>01</sub> =200mA		
Input stability 1	Reg.I1	-	5	30	mV	V <sub>CC</sub> =4.1V→16V,I <sub>O1</sub> =250mA		
Load stability 1	Reg.L1	-	30	75	mV	I <sub>01</sub> =0mA→0.5A		
Temperature coefficient of output voltage 1 <sup>*3</sup>	T <sub>CVO1</sub>	-	±0.01	-	%/°C	I <sub>O1</sub> =5mA,Tj=0°C to 125°C		

## BA33D15HFP Vo2 output

[1.5V Output Block]						
Output voltage 2	V <sub>O2</sub>	1.470	1.500	1.530	V	I <sub>02</sub> =250mA
Output current capacity 2	I <sub>O2</sub>	0.5	-	-	А	
Ripple rejection 2	R.R.2	50	58	-	dB	f=120Hz,ein=1Vp-p,I <sub>O2</sub> =200mA
Input stability 2	Reg.l2	-	5	30	mV	V <sub>CC</sub> =4.1V→16V,I <sub>O2</sub> =250mA
Load stability 2	Reg.L2	-	30	75	mV	I <sub>O2</sub> =0mA→0.5A
Temperature coefficient of output voltage 2 <sup>*3</sup>	T <sub>CVO2</sub>	-	±0.01	-	%/°C	I <sub>02</sub> =5mA,Tj=0°C to 125°C

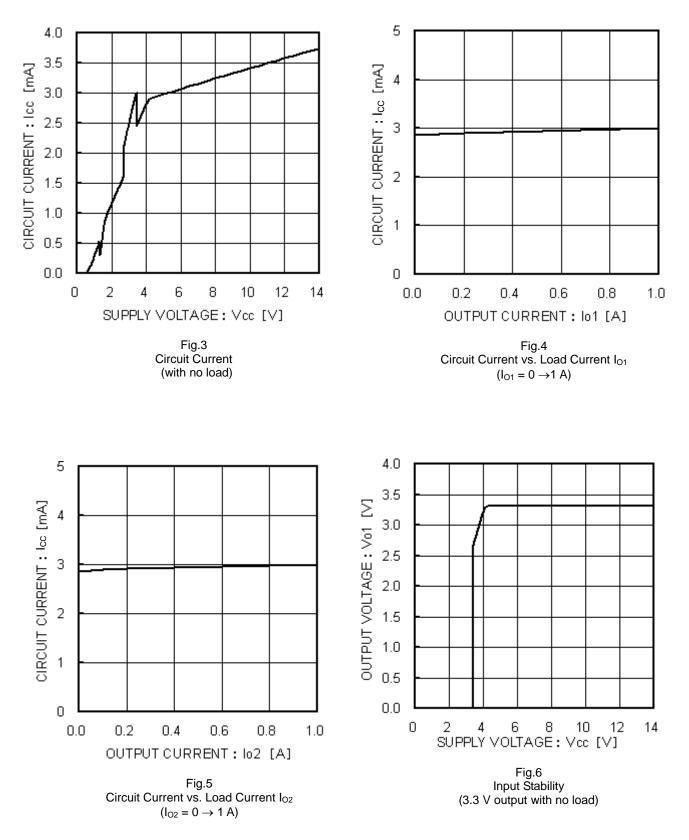
## BA33D18HFP V<sub>02</sub> output

[1.8V Output Block]						
Output voltage 2	V <sub>O2</sub>	1.764	1.800	1.836	V	I <sub>02</sub> =250mA
Output current capacity 2	I <sub>O2</sub>	0.5	-	-	А	
Ripple rejection 2	R.R.2	50	58	-	dB	f=120Hz,ein=1Vp-p,I <sub>O2</sub> =200mA
Input stability 2	Reg.l2	-	5	30	mV	V <sub>CC</sub> =4.1V→16V,I <sub>O2</sub> =250mA
Load stability 2	Reg.L2	-	30	75	mV	I <sub>02</sub> =0mA→0.5A
Temperature coefficient of output voltage 2 <sup>*3</sup>	T <sub>CVO2</sub>	-	±0.01	-	%/°C	I <sub>O2</sub> =5mA,Tj=0°C to 125°C

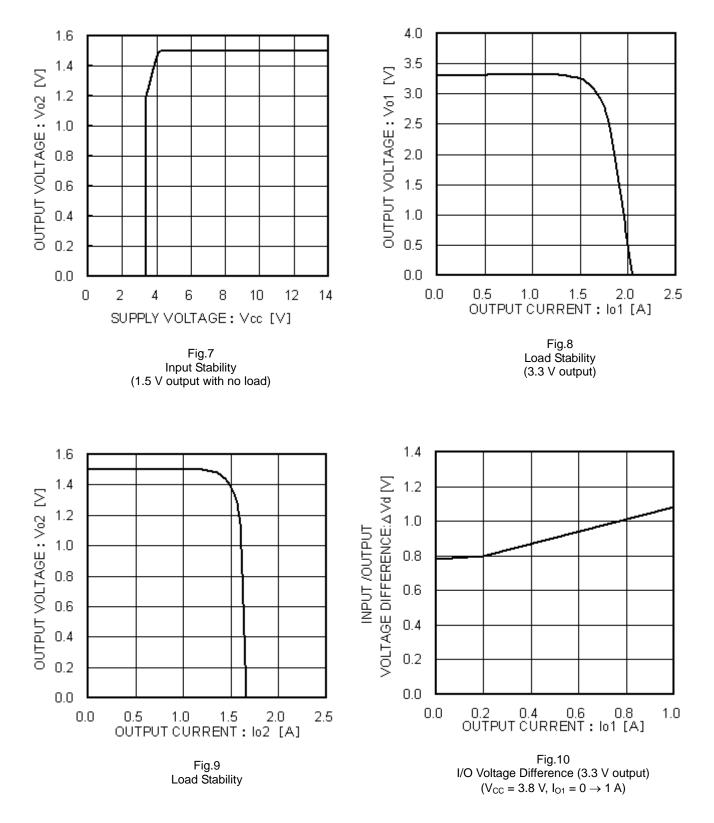
\*3: Not 100% tested.

## Typical Performance Curves

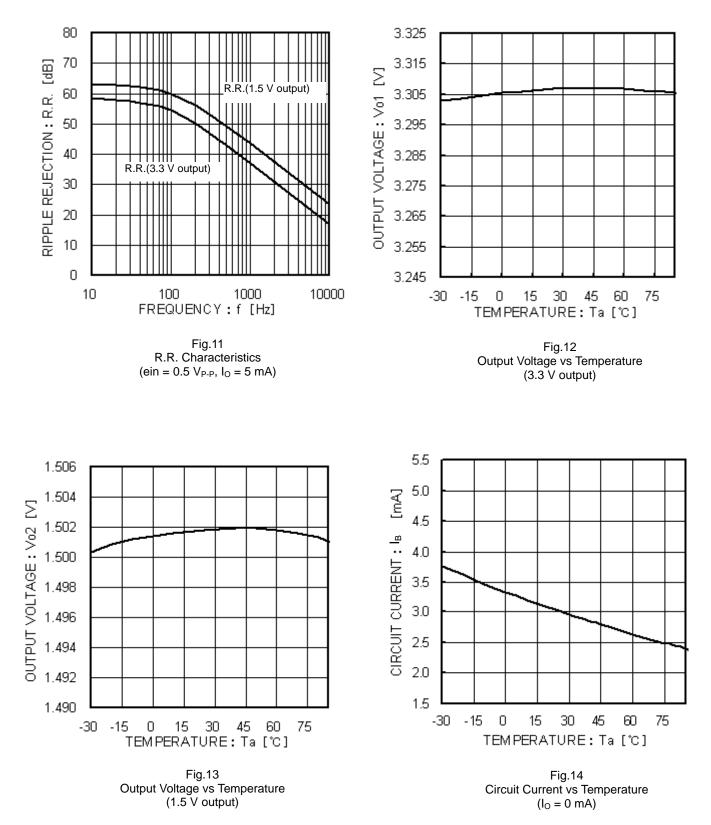
BA3258HFP (Unless otherwise specified, Ta =  $25^{\circ}$ C, V<sub>CC</sub> = 5V)



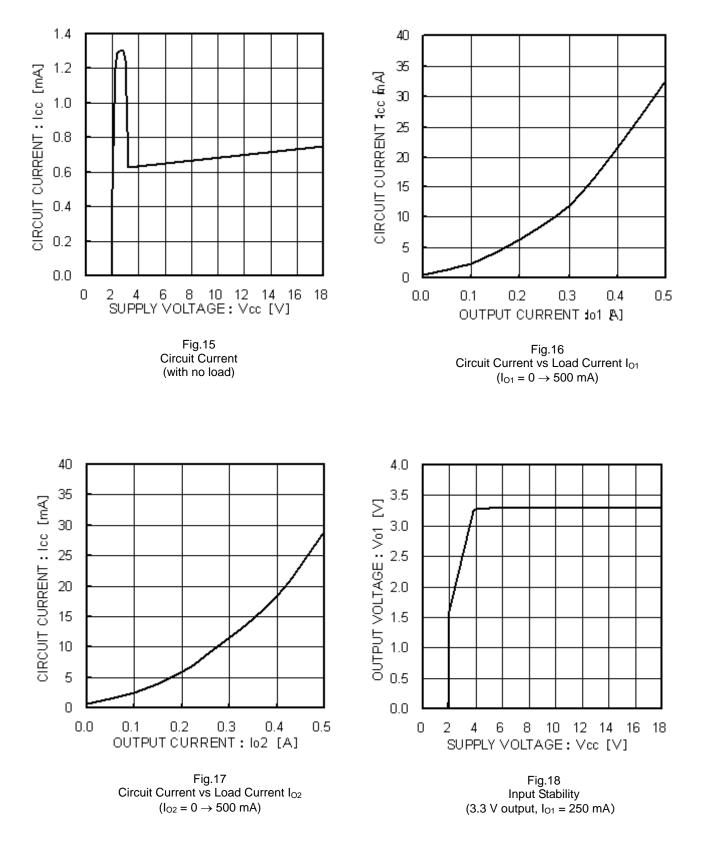
## ●Typical Performance Curves - continued



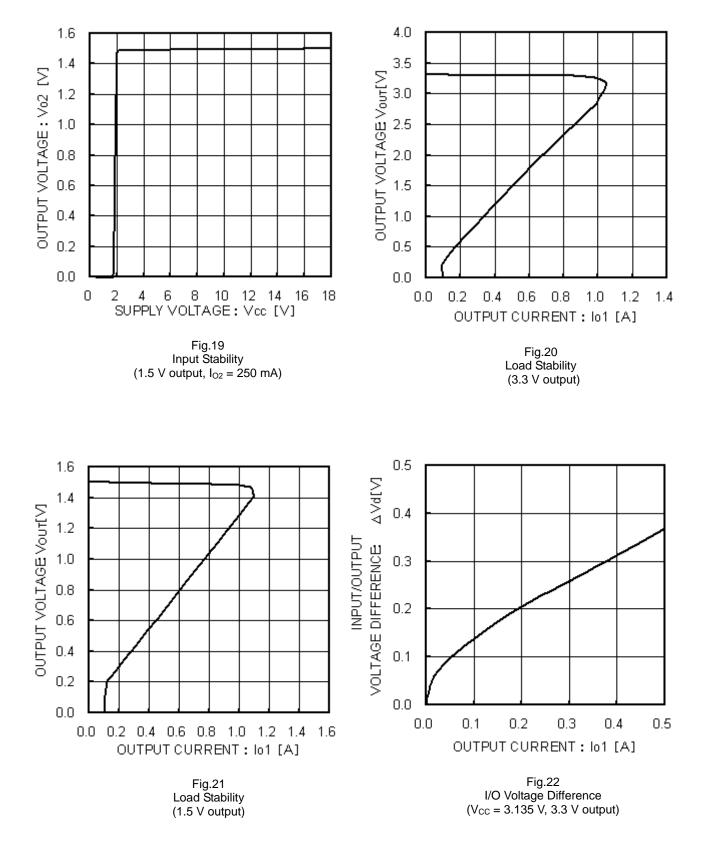
## ●Typical Performance Curves - continued



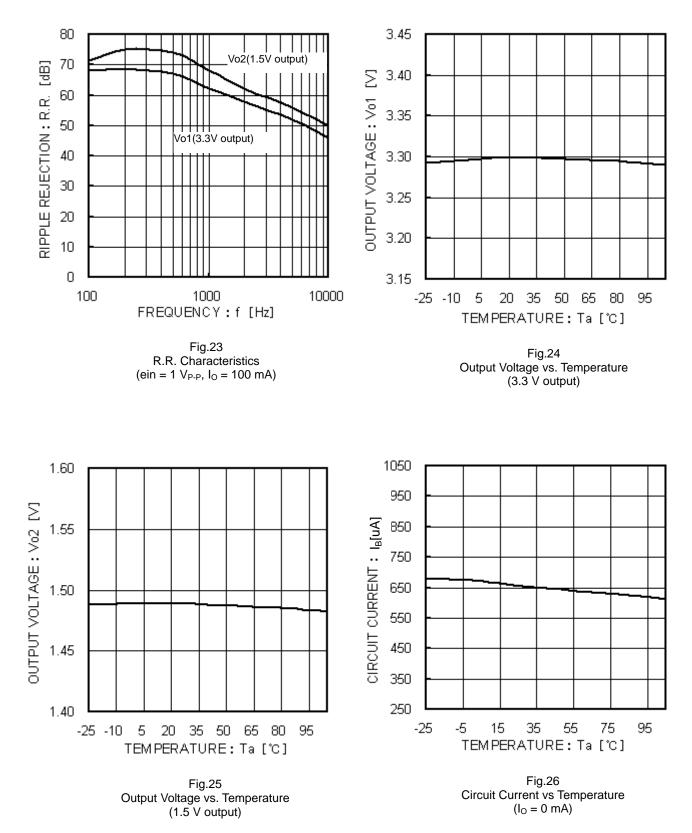
BA33D15HFP (Unless otherwise specified, Ta =  $25^{\circ}$ C, V<sub>CC</sub> = 5V)



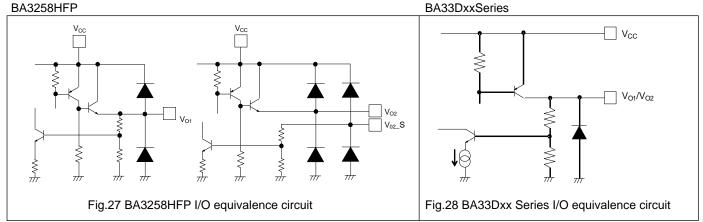
## ●Typical Performance Curves - continued



## Typical Performance Curves - continued



## I/O equivalence circuit

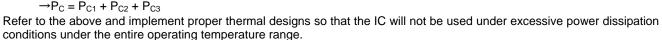


## •Power Dissipation

If the IC is used under excessive power dissipation conditions, the chip temperature will rise, which will have an adverse effect on the electrical characteristics of the IC, such as a reduction in current capability. Furthermore, if the temperature exceeds Tjmax, element deterioration or damage may occur. Implement proper thermal designs to ensure that the power dissipation is within the permissible range in order to prevent instantaneous IC damage resulting from heat and maintain the reliability of the IC for long-term operation. Refer to the power derating characteristics curves in Fig.29.

Vcc

- Power Consumption (Pc) Calculation Method
- Power consumption of 3.3V power transistor:  $P_{C1}$  = (V\_{CC} – 3.3)  $\times$   $I_{O1}$
- Power consumption of V<sub>O2</sub> power transistor:  $P_{C2} = (V_{CC} - V_{O2}) \times I_{O2}$



lcc ↓

GND

Controlle

Calculation example (BA33D15HFP)

- Example:  $V_{CC} = 5V$ ,  $I_{O1} = 200$ mA, and  $I_{O2} = 100$ mA
- Power consumption of 3.3V power transistor:
- · Power consumption of 1.5V power transistor:
- Power consumption due to circuit current:

$$\begin{split} P_{C1} &= (V_{CC} - 3.3) \times I_{O1} = (5 - 3.3) \times 0.2 = 0.34W \\ P_{C2} &= (V_{CC} - 1.5) \times I_{O2} = (5 - 1.5) \times 0.2 = 0.35W \\ P_{C3} &= V_{CC} \times I_{CC} = 5 \times 0.0085 = 0.0425 \text{ (W)} \text{ (See Fig.16 and 17)} \end{split}$$

3.3 V output

lo<sub>2</sub>

1.5 V output or

1.8 V output

Voi

V<sub>O2</sub>

Power Tr

\*V<sub>CC</sub>: Applied voltage I<sub>01</sub>:Load current on V<sub>01</sub> side

I<sub>CC</sub>:Circuit current

 $I_{O2}$ :Load current on  $V_{O2}$  side

The  $I_{\text{CC}}$  (circuit current) varies with the load.

(See reference data in Fig.4, 5, 16, and 17.)

Implement proper thermal designs taking into consideration the dissipation at full power consumption (i.e.,  $P_{C1} + P_{C2} + P_{C3} = 0.34 + 0.35 + 0.0425 = 0.7325W$ ).

## Explanation of External Components

- OBA3258HFP
- 1) Pin 1 (V<sub>CC</sub> pin)

Connecting a ceramic capacitor with a capacitance of approximately  $3.3\mu$ F between V<sub>CC</sub> and GND as close to the pins as possible is recommended.

2) Pins 4 and 5 ( $V_0$  pins)

Insert a capacitor between the Vo and GND pins in order to prevent output oscillation. The capacitor may oscillate if the capacitance changes as a result of temperature fluctuations. Therefore, it is recommended that a ceramic capacitor with a temperature coefficient of X5R or above and a maximum capacitance change (resulting from temperature fluctuations) of  $\pm 10\%$  be used. The capacitance should be between 1µF and 1,000µF. (Refer to Fig.30)

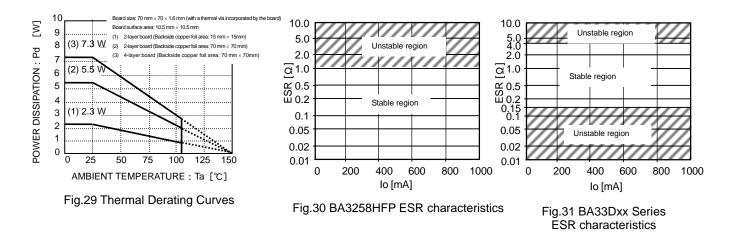
OBA33DxxSeries

1) Pin 1 (V<sub>CC</sub> pin)

Insert a  $1\mu$ F capacitor between V<sub>CC</sub> and GND. The capacitance will vary depending on the application. Check the capacitance with the application set and implement designing with a sufficient margin.

2) Pins 4 and 5 ( $V_0$  pins)

Insert a capacitor between the V<sub>o</sub> and GND pins in order to prevent oscillation. The capacitance may vary greatly with temperature changes, thus making it impossible to completely prevent oscillation. Therefore, use a tantalum aluminum electrolytic capacitor with a low ESR (Equivalent Serial Resistance). The output will oscillate if the ESR is too high or too low, so refer to the ESR characteristics in Fig.31 and operate the IC within the stable operating region. If there is a sudden load change, use a capacitor with higher capacitance. A capacitance between  $10\mu$ F and  $1,000\mu$ F is recommended.



## Operational Notes

1) Absolute maximum ratings

An excess in the absolute maximum ratings, such as supply voltage, temperature range of operating conditions, etc., can break down the devices, thus making impossible to identify breaking mode, such as a short circuit or an open circuit. If any over rated values will expect to exceed the absolute maximum ratings, consider adding circuit protection devices, such as fuses.

2) GND voltage

The potential of GND pin must be minimum potential in all operating conditions.

3) Thermal Design

Use a thermal design that allows for a sufficient margin in light of the power dissipation (Pd) in actual operating conditions.

4) Inter-pin shorts and mounting errors

Use caution when positioning the IC for mounting on printed circuit boards. The IC may be damaged if there is any connection error or if pins are shorted together.

- Actions in strong electromagnetic field Use caution when using the IC in the presence of a strong electromagnetic field as doing so may cause the IC to malfunction.
- 6) Testing on application boards

When testing the IC on an application board, connecting a capacitor to a pin with low impedance subjects the IC to stress. Always discharge capacitors after each process or step. Always turn the IC's power supply off before connecting it to or removing it from a jig or fixture during the inspection process. Ground the IC during assembly steps as an antistatic measure. Use similar precaution when transporting or storing the IC.

7) Regarding input pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of these P layers with the N layers of other elements, creating a parasitic diode or transistor. For example, the relation between each potential is as follows:

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.

When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes can occur inevitable in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Accordingly, methods by which parasitic diodes operate, such as applying a voltage that is lower than the GND (P substrate) voltage to an input pin, should not be used.

## 8) Ground Wiring Pattern

When using both small signal and large current GND patterns, it is recommended to isolate the two ground patterns, placing a single ground point at the ground potential of application so that the pattern wiring resistance and voltage variations caused by large currents do not cause variations in the small signal ground voltage. Be careful not to change the GND wiring pattern of any external components, either.

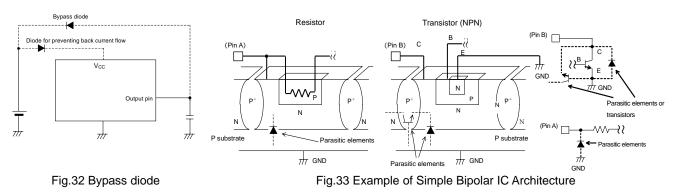
9) Thermal Shutdown Circuit (TSD)

This IC incorporates a built-in thermal shutdown circuit for protection against thermal destruction. Should the junction temperature (Tj) reach the thermal shutdown ON temperature threshold, the TSD will be activated, turning off all output power elements. The circuit will automatically reset once the chip's temperature Tj drops below the threshold temperature. Operation of the thermal shutdown circuit presumes that the IC's absolute maximum ratings have been exceeded. Application designs should never make use of the thermal shutdown circuit.

10) Overcurrent protection circuit

An overcurrent protection circuit is incorporated in order to prevention destruction due to short-time overload currents. Continued use of the protection circuits should be avoided. Please note that the current increases negatively impact the temperature.

11) Damage to the internal circuit or element may occur when the polarity of the V<sub>CC</sub> pin is opposite to that of the other pins in applications. (I.e. V<sub>CC</sub> is shorted with the GND pin while an external capacitor is charged.) Use a maximum capacitance of 1000 mF for the output pins. Inserting a diode to prevent back-current flow in series with V<sub>CC</sub> or bypass diodes between V<sub>CC</sub> and each pin is recommended.



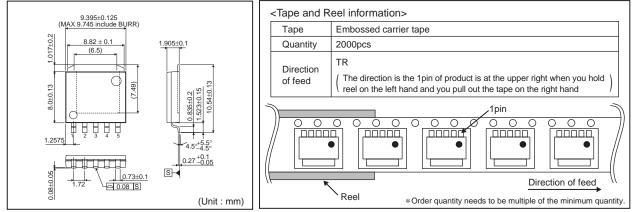
Status of this document

The Japanese version of this document is formal specification. A customer may use this translation version only for a reference to help reading the formal version.

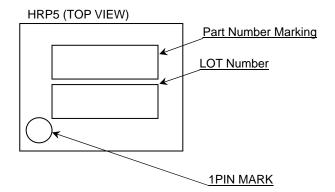
If there are any differences in translation version of this document formal version takes priority.

## Physical Dimension Tape and Reel Information

## HRP5



## Marking Diagram



Part Number	Package	Part Number Marking
BA3258HFP	HRP5	BA3258
BA33D15HFP	HRP5	BA33D15
BA33D18HFP	HRP5	BA33D18

## Revision History

Date	Revision	Changes
26.Jun.2012	001	New Release

## Notice

## Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment <sup>(Note 1)</sup>, transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

JAPAN		USA	EU	CHINA	
CLASSⅢ			CLASS II b		
	CLASSⅣ	CLASSⅢ	CLASSⅢ	CLASSⅢ	

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
  - [a] Installation of protection circuits or other protective devices to improve system safety
  - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
  - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [C] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

## Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

## **Precautions Regarding Application Examples and External Circuits**

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### **Precaution for Storage / Transportation**

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

#### **Precaution for Product Label**

QR code printed on ROHM Products label is for ROHM's internal use only.

#### Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

#### Precaution for Foreign Exchange and Foreign Trade act

Since our Products might fall under controlled goods prescribed by the applicable foreign exchange and foreign trade act, please consult with ROHM representative in case of export.

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